



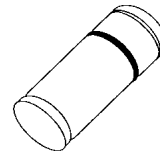
TMMBAT 47 TMMBAT 48

SMALL SIGNAL SCHOTTKY DIODES

DESCRIPTION

General purpose, metal to silicon diodes featuring very low turn-on voltage and fast switching.

These devices have integrated protection against excessive voltage such as electrostatic discharges.



MINIMELF
(Glass)

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		TMMBAT47	TMMBAT48	Unit
V _{RRM}	Repetitive Peak Reverse Voltage		20	40	V
I _F	Forward Continuous Current	T _I = 25 °C	350		mA
I _{FRM}	Repetitive Peak Fordward Current	t _p ≤ 1s δ ≤ 0.5	1		A
I _{FSM}	Surge non Repetitive Forward Current	t _p = 10ms	7.5		A
		t _p = 1s	1.5		
P _{tot}	Power Dissipation	T _I = 25 °C	330		mW
T _{stg} T _j	Storage and Junction Temperature Range		- 65 to 150 - 65 to 125		°C °C
T _L	Maximum Temperature for Soldering during 15s		260		°C

THERMAL RESISTANCE

Symbol	Test Conditions	Value	Unit
$R_{th(j-l)}$	Junction-leads	300	$^{\circ}\text{C/W}$

TMMBAT 47/TMMBAT 48

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
V _{BR}	T _J = 25°C	I _R = 10μA	TMMBAT47	20			V
	T _J = 25°C	I _R = 25μA	TMMBAT48	40			
V _F [*]	T _J = 25°C	I _F = 0.1mA	All Types			0.25	V
	T _J = 25°C	I _F = 1mA				0.3	
	T _J = 25°C	I _F = 10mA				0.4	
	T _J = 25°C	I _F = 30mA	TMMBAT47			0.5	
	T _J = 25°C	I _F = 150mA				0.8	
	T _J = 25°C	I _F = 300mA				1	
	T _J = 25°C	I _F = 50mA	TMMBAT48			0.5	
	T _J = 25°C	I _F = 200mA				0.75	
	T _J = 25°C	I _F = 500mA				0.9	
	I _R [*]	T _J = 25°C	V _R = 1.5V	All Types			
T _J = 60°C						10	
T _J = 25°C		V _R = 10V	TMMBAT47			4	
T _J = 60°C						20	
T _J = 25°C		V _R = 20V				10	
T _J = 60°C						30	
T _J = 25°C		V _R = 10V	TMMBAT48			2	
T _J = 60°C						15	
T _J = 25°C		V _R = 20V				5	
T _J = 60°C						25	
T _J = 25°C		V _R = 40V				25	
T _J = 60°C						50	

DYNAMIC CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
C	$T_j = 25^{\circ}\text{C}$	$V_R = 0\text{V}$	f = 1MHz		20		pF
	$T_j = 25^{\circ}\text{C}$	$V_R = 1\text{V}$			12		
t_{rr}	$T_j = 25^{\circ}\text{C}$	$I_F = 10\text{mA}$	$V_R = 1\text{V}$	$i_{rr} = 1\text{mA}$	$R_L = 100\Omega$	10	ns

* Pulse test: $t_p \leq 300\mu\text{s}$ $\delta < 2\%$.

Figure 1. Forward current versus forward voltage at different temperatures (typical values).

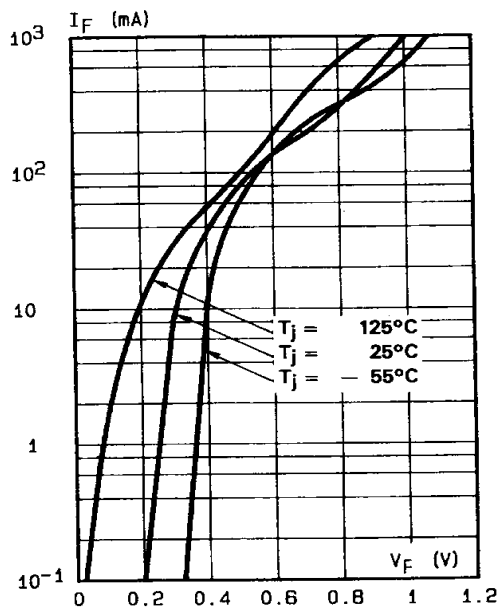


Figure 2. Forward current versus forward voltage (typical values).

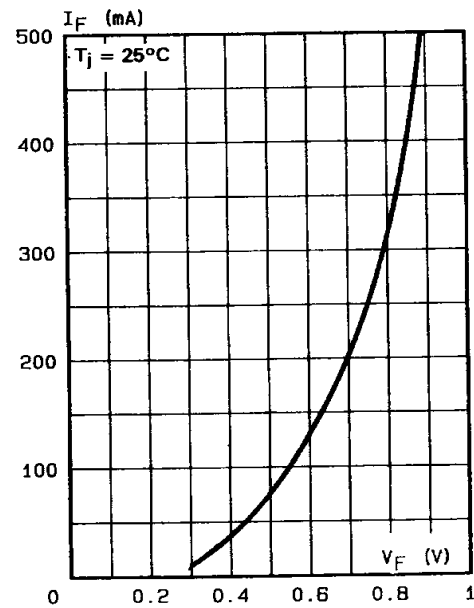


Figure 3. Reverse current versus junction temperature.

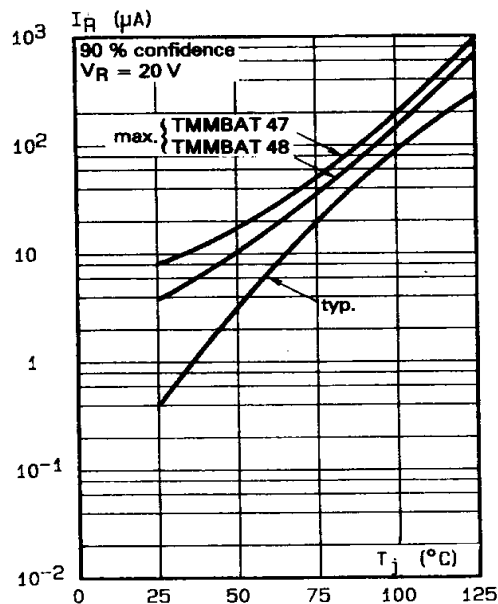


Figure 4. Reverse current versus continuous reverse voltage (typical values).

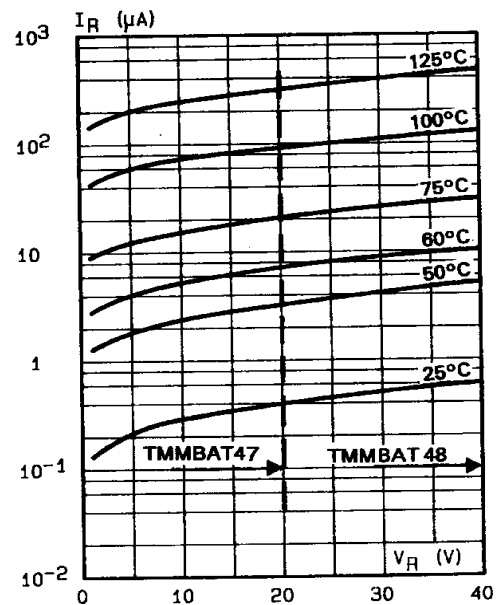
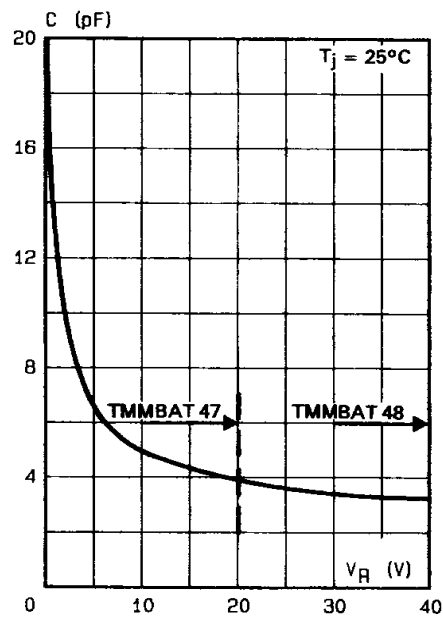
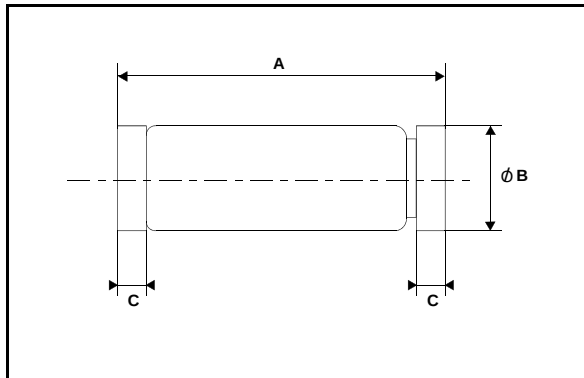


Figure 5. Capacitance C versus reverse applied voltage V_R (typical values).



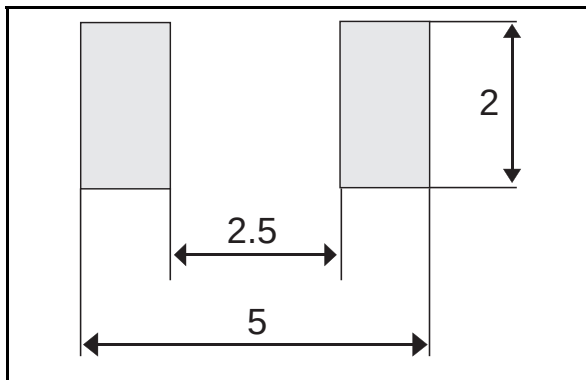
PACKAGE MECHANICAL DATA

MINIMELF Glass



REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	3.30	3.40	3.6	0.130	0.134	0.142
B	1.59	1.60	1.62	0.063	0.063	0.064
C	0.40	0.45	0.50	0.016	0.018	0.020
D		1.50			0.059	

FOOT PRINT DIMENSIONS (Millimeter)



Marking: ring at cathode end.
Weight: 0.05g

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